ABSTRACT

Many engineers face the challenge of amplifying small signals produced by sensors with high source impedance in a low-noise circuit. Amplifier circuit design for sensor applications such as hydrophones, guitar pickups, high source impedance microphones, and turntables can benefit from a combination of discrete components and operational amplifiers. This application note discusses the use of JFET and Operational Amplifiers (op amps) in a composite amplifier configuration to accomplish this design challenge.

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1 Introduction

Amplifying the small signals produced by sensors in a low-noise circuit is a very common but difficult problem. This was outlined in the JFE150 Ultra-Low-Noise Pre-Amp application note. High source impedance sensors such as a microphone, that produce signals on the order of a few thousandths of a volt, are loaded by low noise and low input impedance bipolar junction transistor (BJT) stages. Using a complementary metal-oxide semiconductor (CMOS) device is a good choice for a high input impedance; however, the noise performance is worse than that of a bipolar input. The discrete junction field-effect transistor (JFET) has better noise performance than the CMOS device and also has high input impedance. More details are found in the Tradeoffs Between CMOS, JFET, and Bipolar Input Stage Technology application report. A discrete JFET such as TI’s JFE2140, when followed by a bipolar op amp such as the OPA202, offers a way to achieve high input impedance and low noise with flexible biasing, see Figure 1-1.

![Figure 1-1. Preamplifier With JFE2140 Front End in a Closed-Loop Circuit](image-url)
2 Theory of Operation

The JFET preamplifier (preamp) circuit is easiest to analyze using the small-signal T-model as shown in Figure 2-1. To understand the operation of this circuit, begin by examining the preamp at the input. A sensor generates a small-signal input voltage \(v_{\text{in}}\), which modulates the gate-to-source voltage \(v_{\text{gs}}\) of the JFET. The JFE2140 is the first gain stage in the preamp circuit and conducts a small-signal drain-to-source current \(i_{\text{ds1}} = g_{\text{m1}} \times v_{\text{gs1}}\) that fluctuates with \(v_{\text{in}}\). The transconductance gain parameter \((g_{\text{m}})\), is expressed in Siemens and \(v_{\text{gs}}\) is expressed in volts.

![Figure 2-1. Preamp With JFE2140 Front End Small Signal T-Model](image)

The small-signal current \(i_{\text{ds1}}\) flows through resistors \(R_{\text{D1}}\) and \(R_{\text{D2}}\) forming a differential voltage \(v_{\text{od}}\) between the drains of the JFE2140. The OPA202 monitors \(v_{\text{od}}\) and drives the loop with voltage \(v_{\text{out}}\) such that the inputs of the OPA202 are approximately equal. The JFE2140 combined with the OPA202 form the feedforward gain stage A shown in Figure 2-1. Assuming symmetry and \(i_{\text{ds1}} = i_{\text{ds2}}\), the gain of the JFE2140 is \(g_{\text{m}} \times R_{\text{D}}\). The transconductance parameter \(g_{\text{m}}\) can be approximated from Figure 2-2. At a drain-to-source current of 1 mA, the measured \(g_{\text{m}}\) is approximately 7.5 mS.
The DC $A_{cl}$ of the OPA202 is 150 dB. Combined with the JFET gain, the resulting feedforward gain $A$ is calculated as shown in Equation 1. The simulated feedforward gain is shown in Figure 2-3 and is $A = 175$ dB. This closely matches the calculated result.

$$A_{dB} = 20 \times \log(7.5 \text{ mS} \times 2.5 \text{ k}\Omega) + 150 \text{ dB} = 175.46 \text{ dB}$$

(1)

![Figure 2-2. Transconductance vs Drain-To-Source Current](image)

![Figure 2-3. Loop Parameters (dB) vs Frequency (Hz)](image)
Because wafer process variations can yield up to 30% variations in $g_m$, adding a feedback network ($\beta$) maintains a predictable closed-loop gain. The $\beta$ feedback network consists of resistors $R_F$ and $R_{G2}$ and is a series-shunt feedback network. The $\beta$ network samples $v_{out}$ by shunting the output of the OPA202 and feeds back a proportional voltage $v_{fb}$. The voltage $v_{fb} = v_{gs2}$. The gate is the feedback-summing node of the circuit. In this configuration, the loop is closed. An increase of the input differential voltage $v_{id}$ results in a rise of $v_{od}$ and therefore $v_{out}$. If $v_{out}$ rises, then $v_{gs2}$ rises. An increase of $v_{gs2}$ lowers $v_{id}$. A decrease of the differential voltage between the JFET drains is observed. The final outcome is a reduction of $v_{out}$ which completes the negative feedback loop of the preamplifier.

The standard closed-loop gain ($A_{cl}$) Equation 2 applies.

$$A_{cl} = \frac{A}{1 + A\beta}$$  \hspace{1cm} (2)

Assuming the feedforward gain $A$ is much greater than $\beta$, $A_{cl}$ is approximately determined by resistors $R_F$ and $R_{G2}$ in the mid-band frequencies. $A_{cl}$ can be approximately calculated using Equation 3.

$$A_{cl} \approx \frac{1}{\beta} = \frac{R_F}{R_{G2}} + 1$$  \hspace{1cm} (3)

$$A_{cl} \approx 1001 \frac{V}{V} \textrm{ or } 60 \text{ dB}$$  \hspace{1cm} (4)

Figure 2-4 shows the closed-loop gain vs frequency response of the JFET preamplifier circuit.
Figure 2-5 compares the gain bandwidth of the JFE2140 composite preamp circuit to the OPA202 and the OPA145. Each configuration is in a gain of 60 dB. Table 2-1 shows that the JFE2140 composite preamp circuit achieves the highest bandwidth of the 3 circuits. This is made possible by the additional feedforward gain that the discrete JFET front end contributes. Table 2-1 also shows the ultra-low-noise performance that the JFE2140 composite circuit achieves.
3 Stability

The loop parameters $A$, and $1/\beta$ can be determined in simulation by breaking the loop. This is accomplished in a SPICE simulator by driving the loop with $V_{\text{Loop}}$ as shown in Figure 3-1.

![A Circuit](image)

Figure 3-1. Loop Analysis for Preamp With JFE2140 Front End Using the Small-Signal T-Model

At high frequencies the inductor $L_1$ is an open and the capacitor $C_2$ is a short. This method isolates the circuits $A$ and $\beta$, to plot the frequency response of each, as shown in Figure 3-2.
The upper −3 dB point of $A_{cl}$ occurs when $A$ and $1/\beta$ meet. Breaking the loop also allows the designer to check for circuit stability as shown with the loop gain ($A \times \beta$) phase plot in Figure 3-2. At the point of intersection of $A$ and $1/\beta$, the phase margin = $180^\circ – 90^\circ = 90^\circ$. A capacitor placed across resistor $R_F$ in the $\beta$ circuit can improve stability in applications that are susceptible to instability. Applications that drive heavy capacitive loads can benefit from an isolation resistor placed outside the loop on $v_{out}$. 

**Figure 3-2. Stability Analysis**
4 Summary

Amplification of small signals in applications such as professional microphones, audio interfaces, mixers, turntables, and guitar amplifiers is very challenging. These types of applications benefit from the bias flexibility, high-input impedance, and low noise that a discrete JFET offers.
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